## [T-13]

## Properties Comparision of TiO<sub>2</sub> and TiO-N made by Reactive Magnetron Sputtering

Jang Sick Park, Sang Won Park\*, Tae Woo Kim, Sung Kuk Kim\* and Won Sul Ahn\* Mirae engineering co. ltd, \* Department of Environmental Science, Keimyung University

TiO<sub>2</sub> having high photocatalystic property in UV wavelength region is studied by many researchers for using in visible wavelength region because it uses below 5% of sun energy. It is noticed photocatalystic activity by N doping in the TiO<sub>2</sub> (TiO-N) is higher in visible light region than that of TiO<sub>2</sub><sup>(1)</sup>. Thin films are made at 300 °C by DC reactive magnetron sputtering methode using Ar, O<sub>2</sub> and N<sub>2</sub> gas in Ti Target that 0.6kw~5.8kw power is impressed. It is inspected that hysteresis phenomenon of TiO<sub>2</sub> thin film in discharge voltage characteristics is high as power is high and hysteresis phenomenon in TiO-N thin film is occurred in the 5.8kw power. Surface roughness of TiO-N thin films is larger than that of TiO<sub>2</sub> thin films . The results of XPS analysis and optical absorption spectra will be reported.

[참고문헌]

R. Asahi, T. Morikawa, T. Ohwaki, K. Aoki and Y. Taga, Science, 293 (2001) 269